SOT-23

1. GATE

2. SOURCE

3. DRAIN



2N7002 MOSFET (N-Channel)

FEATURES

- High density cell design for low R_{DS(ON)}
- Voltage controlled small signal switch
- Rugged and reliable
- High saturation current capability



Marking: 7002

MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Symbol	Parameter	Value	Units	
V _{DS}	Drain-Source voltage	60	V	
I _D	Drain Current	115	mA	
P _D	Power Dissipation	225	mW	
R _{OJA}	Thermal Resistance, junction to Ambient	556	°C/W	
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature	-55-150	$^{\circ}$ C	

ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

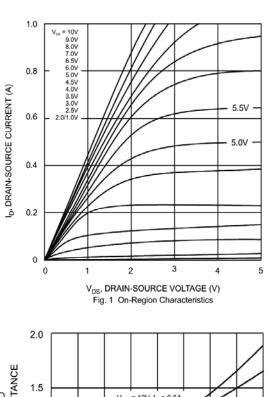
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Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0 V, I _D =10 μA	60			V
Gate-Threshold Voltage	V _{th(GS)}	V _{DS} =V _{GS} , I _D =250 μA	1		2.5	
Gate-body Leakage	I _{GSS}	V_{DS} =0 V, V_{GS} = \pm 25 V			±8 0	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60 V, V _{GS} =0 V			80	nA
On-state Drain Current	I _{D(ON)}	V _{GS} =10 V, V _{DS} =7 V	500			mA
Drain-Source On-Resistance	r _{DS(0n)}	V _{GS} =10 V, I _D =500mA	1		7.5	Ω
Diam-Source On-Resistance		V _{GS} =5 V, I _D =50mA	1		7.5	
Forward Trans conductance	g _{fs}	V _{DS} =10 V, I _D =200mA	80		500	ms
Drain course on voltage	V _{DS(on)}	V _{GS} =10V, I _D =500mA	0.5		3.75	V
Drain-source on-voltage		V _{GS} =5V, I _D =50mA	0.05		0.375	V
Diode Forward Voltage	V _{SD}	I _S =115mA, V _{GS} =0 V	0.55		1.2	V
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1MHz			50	pF
Output Capacitance	Coss				25	
Reverse Transfer Capacitance	C _{rSS}				5	

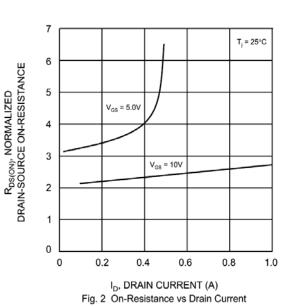
SWITCHING TIME

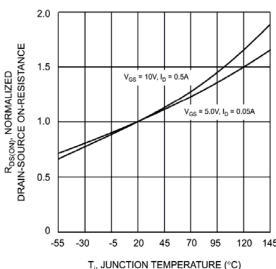
Turn-on Time	t _{d(on)}	V_{DD} =25 V, R_L =50 Ω		20	no
Turn-off Time	t _{d(off)}	I_D =500mA, V_{GEN} =10 V R_G =25 Ω		40	ns



Typical characteristics







6
5
4
I_o = 50mA
3
2
1
0
0
2
4
6
8
10
12
14
16
18

 T_{j} , JUNCTION TEMPERATURE (°C) Fig. 3 On-Resistance vs Junction Temperature

V_{GS}, GATE TO SOURCE VOLTAGE (V) Fig. 4 On-Resistance vs. Gate-Source Voltage

R_{DS(ON)}, NORMALIZED DRAIN-SOURCE ON-RESISTANCE www.s-manuals.com